

Application Specific Discretes A.S.D.™

ESDA17/19-5SC6

TRANSIL™ ARRAY FOR ESD PROTECTION

APPLICATIONS

Where transient overvoltage protection in ESD sensitive equipment is required, such as :

- Computers
- Printers and other peripherals
- Communications systems
- Cellular phone handsets and accessories
- Other telephone sets
- Consumer Electronics (Set top boxes, DVD players, TV sets)

DESCRIPTION

The ESDA17/19-5SC6 is a monolithic array designed to protect up to 5 lines against ESD transients.

The device is ideal for applications where board space savind is required.

FEATURES

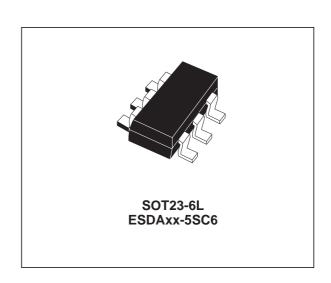
- 5 Unidirectional transil[™] functions
- Minimum breakdown voltage range v_{BRmin} = 17V or 19V
- Peak pulse power (8/20µs); 150W
- Tiny leakage current at stand-off voltage: < 100nA</p>

BENEFITS

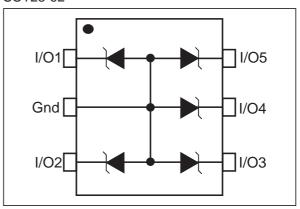
- High ESD protection level
- High integration
- Suitable for high density boards

COMPLIES WITH THE FOLLOWING STANDARDS:

- IEC61000-4-2: 15 kV (air discharge) 8 kV (contact discharge)
- MIL STD 883E-Method 3015-7: class3 25kV (human body model)



FUNCTIONAL DIAGRAM SOT23-6L



November 2002 - Ed: 1A 1/5

ESDA17/19-5SC6

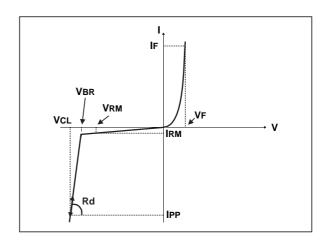
ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25°C)

Symbol	Test conditions	Value	Unit
V _{PP}	ESD discharge - IEC61000-4-2 air dischar IEC61000-4-2 contact dis	± 15 ± 8	kV
P _{PP}	Peak pulse power dissipation (8/20μs) Note 1	150	W
Tj	Junction temperature	125	°C
T _{stg}	Storage temperature range	-55 to +150	°C
TL	Maximum lead temperature for soldering dur case	260	°C
T _{op}	Operating temperature range	-40 to +125	°C

Note 1: For a surge greater than the maximum values, the diode will fail in short-circuit.

ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C)

Symbol	Parameter				
V_{RM}	Stand-off voltage				
V_{BR}	Breakdown voltage				
V _{CL}	Clamping voltage				
I _{RM}	Leakage current @ V _{RM}				
I _{PP}	Peak pulse current				
αΤ	Voltage temperature coefficient				
V _F	Forward voltage drop				



	V	BR @	I R	I _{RM} @	V _{RM}	Rd	αT	С	V _F (@ ⊫
Type	min.	max.					max.	typ.	max.	
Турс						note 1	note 2	0V bias		
	V	V	mA	nA	V	Ω	10 ⁻⁴ /°C	рF	V	mΑ
ESDA17-5SC6	17	19	1	75	14	1	10	33	1.2	10
ESDA19-5SC6	19	21	1	100	15	1	8.5	33	1.2	10

Note 1 : Square pulse, Ipp = 15A, tp=2.5 μ s. Note 2: Δ VBR = α T* (Tamb-25°C) * VBR(25°C)

Fig. 1: Relative variation of peak pulse power versus initial junction temperature.

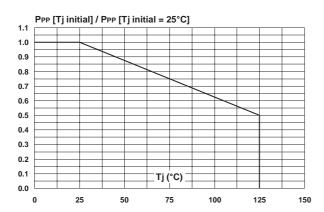


Fig. 2: Peak pulse power versus exponential pulse duration.

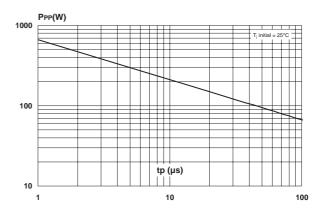


Fig. 3: Clamping voltage versus peak pulse current (typical values, rectangular waveform).

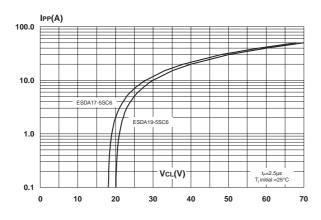


Fig. 4: Forward voltage drop versus peak forward current (typical values).

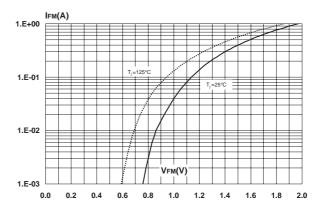


Fig. 5: Junction capacitance versus reverse voltage applied (typical values).

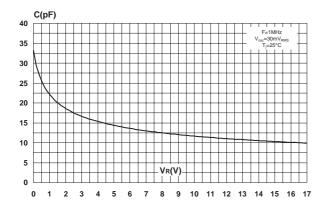
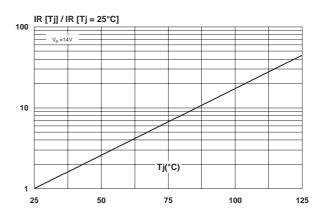
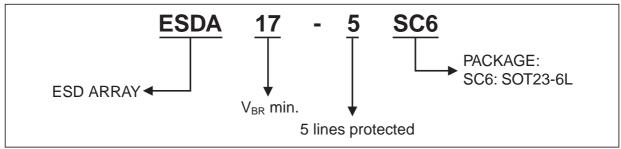


Fig. 6: Relative variation of leakage current versus junction temperature (typical values).



47

ORDER CODE



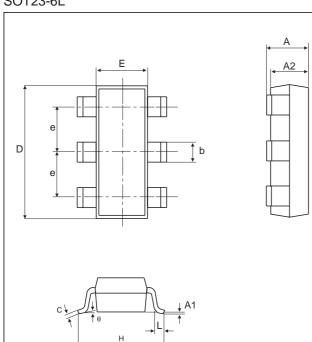
OTHER INFORMATIONS

Туре	Marking	Package	Weight	Base Qty	Delivery mode
ESDA17-5SC6	175	SOT23-6L	16.7mg	3000	Tape & Reel
ESDA19-5SC6	195	SOT23-6L	16.7mg	3000	Tape & Reel

■ Epoxy meets UL94, V0

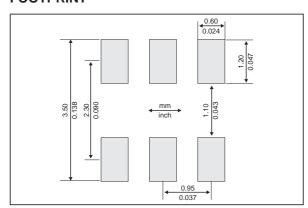
4/5

PACKAGE MECHANICAL DATA SOT23-6L



REF.	DIMENSIONS							
	Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α	0.90		1.45	0.035		0.057		
A1	0		0.10	0		0.004		
A2	0.90		1.30	0.035		0.0512		
b	0.35		0.50	0.0137		0.02		
С	0.09		0.20	0.004		0.008		
D	2.80		3.00	0.11		0.118		
Е	1.50		1.75	0.059		0.0689		
е		0.95			0.0374			
Н	2.60		3.00	0.102		0.118		
L	0.10		0.60	0.004		0.024		
θ			10°			10°		

FOOTPRINT



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